NSN 5961-01-215-5984

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No



View Online at https://aerobasegroup.com/nsn/5961-01-215-5984

Inclosure Material:
Metal
Overall Length:
Between 1.188 inches and 1.252 inches
Overall Height:
Between 0.610 inches and 0.840 inches
Overall Width:
0.700 inches
End Application:
1430-01-215-7255
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-275.0 collector to base voltage/static/emitter open and -225.0 collector to emitter voltage/static/base open and -6.0 emitter to base
voltage, static, collector open
Current Rating Per Characteristic:
Between -1.00 amperes source cutoff current and -2.00 amperes source cutoff current
Power Rating Per Characteristic:
200.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Test Data Document:
18876-11437179 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

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